
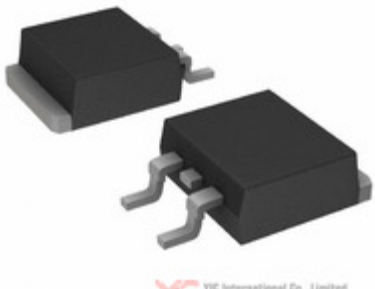
	<p>SUD50N10-18P-E3</p>
	<p>Hersteller-Teilenummer: SUD50N10-18P-E3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 100V 8.2A TO252</p> <hr/> <p>Datenblätter:  SUD50N10-18P-E3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 15138 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD50N10-18P-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 100V 8.2A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	15138 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	3W (Ta), 136.4W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.2A (Ta), 50A (Tc)
Rds On (Max) @ Id, Vgs	18.5 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	75nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2600pF @ 50V
Verpackung	Tape & Reel (TR)



















































SUD50N10-18P-E3 ist neu im Original, Suche SUD50N10-18P-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N10-18P-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD50N10-18P-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N10-34P VISHAY SUD50N10-34P VISHAY</p>	 <p>SUD50N06-36 Vishay SUD50N06-36 Vishay</p>	 <p>SUD50N06-16 VISHAY SUD50N06-16 VISHAY</p>	 <p>SUD50N06-36-T4-E3 VISHAY SUD50N06-36-T4-E3 VISHAY</p>
 <p>SUD50N10-18P-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 100V 8.2A TO252</p>	 <p>SUD50N10-18P VISHAY SUD50N10-18P VISHAY</p>	 <p>SUD50N10-18P-GE3 Vishay / Siliconix MOSFET N-CH 100V 8.2A DPAK</p>	 <p>SUD50N10-18P-T4-E3 VISHAY SUD50N10-18P-T4-E3 VISHAY</p>

heiße Teile

Mehr

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|--|--|--|---|--|
|  SUD50N04-10P-E3 |  SUD50N04-13P |  SUD50N04-13P-E3 |  SUD50N04-16P |  SUD50N04-25P |
|  SUD50N04-37P |  SUD50N04-37P-E3 |  SUD50N04-37P-E3-4GE3 |  SUD50N04-37P-T4-GE3 |  SUD50N04-8M8P |
|  SUD50N04-8M8P-4GE3 |  SUD50N04-8M8P-4GE3 |  SUD50N04-8M8P-E3 |  SUD50N06-07L |  SUD50N06-07L-GE3 |
|  SUD50N06-07L-GE3 |  SUD50N06-08H |  SUD50N06-09L |  SUD50N06-09L-E3 |  SUD50N06-09L-E3 |
|  SUD50N06-16 |  SUD50N06-36 |  SUD50N06L-09 |  SUD50N10-18P |  SUD50N10-18P-E3 |
|  SUD50N10-18P-T4-E3 |  SUD50N10-34P |  SUD50NP04-62-4-E3 |  SUD50NP04-62-T4-E3 |  SUD50NP04-77P |
|  SUD50P04-08 |  SUD50P04-08-GE3 |  SUD50P04-08-GE3 |  SUD50P04-08L |  SUD50P04-09L |
|  SUD50P04-09L-E3 |  SUD50P04-09L-E3 |  SUD50P04-09L-GE3 |  SUD50P04-13L-E3 |  SUD50P04-13L-E3 |
|  SUD50P04-13L-GE3 |  SUD50P04-13L-GE3 |  SUD50P04-15-E3 |  SUD50P04-15-E3 |  SUD50P04-18L |
|  SUD50P04-23 |  SUD50P04-23-E3 |  SUD50P04-23-E3 |  SUD50P04-40P |  SUD50P04-40P-E3 |

Contact us: Info@Y-IC.com

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